

## Vishay Semiconductors

# **Small Signal Fast Switching Diode**



#### **FEATURES**

- · Silicon epitaxial planar diode
- · Electrical data identical with the device 1N4151
- MicroMELF package
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



**HALOGEN** FREE

### **APPLICATIONS**

· Extreme fast switches



### **LINKS TO ADDITIONAL RESOURCES**









#### **MECHANICAL DATA**

Case: MicroMELF

Weight: approx. 12 mg Cathode band color: black Packaging codes / options:

TR3/10K per 13" reel (8 mm tape), 10K/box TR/2.5K per 7" reel(8 mm tape), 12.5K/box

| PARTS TABLE |                         |                           |                       |               |  |
|-------------|-------------------------|---------------------------|-----------------------|---------------|--|
| PART        | TYPE DIFFERENTIATION    | ORDERING CODE             | CIRCUIT CONFIGURATION | REMARKS       |  |
| MCL4151     | V <sub>RRM</sub> = 75 V | MCL4151-TR3 or MCL4151-TR | Single                | Tape and reel |  |

| ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                       |                    |       |      |  |
|---|-----------------------|--------------------|-------|------|--|
| PARAMETER   | TEST CONDITION        | SYMBOL             | VALUE | UNIT |  |
| Repetitive peak reverse voltage   |                       | $V_{RRM}$          | 75    | V    |  |
| Reverse voltage   |                       | V <sub>R</sub>     | 50    | V    |  |
| Peak forward surge current  | t <sub>p</sub> = 1 μs | I <sub>FSM</sub>   | 2     | А    |  |
| Repetitive peak forward current   |                       | I <sub>FRM</sub>   | 450   | mA   |  |
| Forward continuous current  |                       | I <sub>F</sub>     | 200   | mA   |  |
| Average forward current   | V <sub>R</sub> = 0    | I <sub>F(AV)</sub> | 150   | mA   |  |
| Power dissipation   |                       | P <sub>tot</sub>   | 500   | mW   |  |

| THERMAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |                  |             |      |  |  |
|--|---|------------------|-------------|------|--|--|
| PARAMETER  | TEST CONDITION  | SYMBOL           | VALUE       | UNIT |  |  |
| Thermal resistance junction to ambient air                                     | Mounted on epoxy-glass<br>hard tissue, fig. 4,<br>35 µm copper clad, 0.9 mm <sup>2</sup><br>copper area per electrode | $R_{thJA}$       | 500         | K/W  |  |  |
| Junction temperature   |   | Tj               | 175         | °C   |  |  |
| Storage temperature range  |   | T <sub>stg</sub> | -65 to +175 | °C   |  |  |



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| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |                   |      |       |      |      |
|--|---|-------------------|------|-------|------|------|
| PARAMETER  | TEST CONDITION  | SYMBOL            | MIN. | TYP.  | MAX. | UNIT |
| Forward voltage  | I <sub>F</sub> = 50 mA  | V <sub>F</sub>    |      | 0.880 | 1    | V    |
| Reverse current  | V <sub>R</sub> = 50 V   | I <sub>R</sub>    |      |       | 50   | nA   |
| neverse current  | V <sub>R</sub> = 50 V, T <sub>j</sub> = 150 °C  | I <sub>R</sub>    |      |       | 50   | μΑ   |
| Breakdown voltage  | $I_R = 5 \mu A, t_p/T = 0.01,$<br>$t_p = 0.3 \text{ ms}$                                  | V <sub>(BR)</sub> | 75   |       |      | V    |
| Diode capacitance  | $V_R = 0 \text{ V, f} = 1 \text{ MHz,}$<br>$V_{HF} = 50 \text{ mV}$                       | C <sub>D</sub>    |      |       | 2    | pF   |
| Reverse recovery time  | $I_F = I_R = 10 \text{ mA},$ $I_R = 1 \text{ mA}$   | t <sub>rr</sub> - |      |       | 4    | ns   |
| neverse recovery time  | $I_F = 10 \text{ mA}, V_R = 6 \text{ V},$<br>$I_R = 0.1 \text{ x } I_R, R_L = 100 \Omega$ |                   |      |       | 2    |      |

## TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

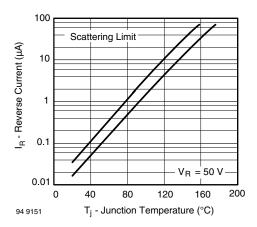


Fig. 1 - Reverse Current vs. Junction Temperature

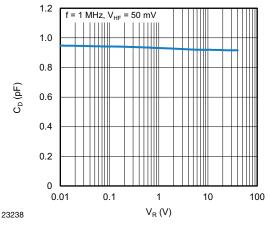


Fig. 3 - Typical Capacitance vs. Reverse Voltage

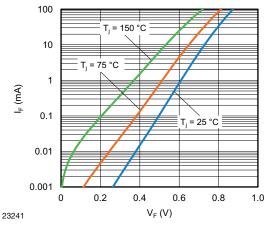


Fig. 2 - Forward Current vs. Forward Voltage

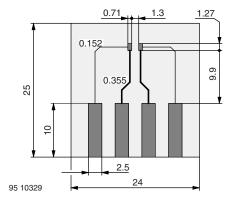
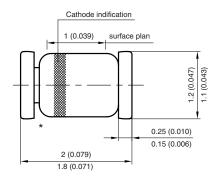


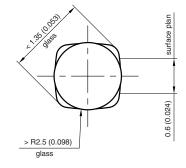
Fig. 4 - Board for R<sub>thJA</sub> Definition (in mm)



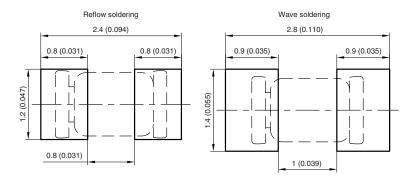
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### PACKAGE DIMENSIONS in millimeters (inches): MicroMELF





#### Foot print recommendation:



Created - Date: 26.July.1996 Rev. 13 - Date: 07.June.2006 Document no.:6.560-5007.01-4 96 12072

<sup>\*</sup> The gap between plug and glass can be either on cathode or anode side



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